## **Vishay Siliconix**

# **Dual Low-Leakage Pico-Amp Diodes**

DPAD1 SSTDPAD5
DPAD5 SSTDPAD100
DPAD50

PRODUCT SUMMARY				
Part Number	I <sub>R</sub> Max (pA)			
DPAD1	-1			
DPAD5/SSTDPAD5	-5			
DPAD50	-50			
SSTDPAD100	-100			

### **FEATURES**

Ultralow Leakage: DPAD1 <1 pA</li>
Ultralow Capacitance: DPAD1 <0.8 pF</li>

## **BENEFITS**

- Negligible Circuit Leakage Contribution
- Circuit "Transparent" Except to Shunt High-Frequency Spikes

## **APPLICATIONS**

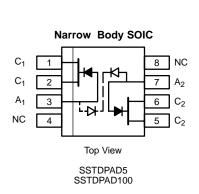
- Op Amp Input Protection
- Multiplexer Overvoltage Protection

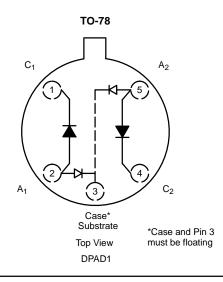
## **DESCRIPTION**

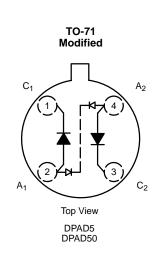
The DPAD/SSTDPAD series of extremely low-leakage diodes provides a superior alternative to conventional diode technology when reverse current (leakage) must be minimized. These devices feature leakage currents ranging from –1 pA (DPAD1) to –100 pA (SSTDPAD100) to support a wide range of applications.

The low-cost, compact, narrow-body SO-8 (SSTDPAD) package allows maximum circuit performance. Tape- and-reel options are avaliable for automated assembly (see Packaging Information).

The TO-78 and TO-71 (DPAD) hermetically sealed metal cans are available with full military processing per MIL-S-19500 (see Military Information).







# **DPAD/SSTDPAD Series**

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## **ABSOLUTE MAXIMUM RATINGS<sup>a</sup>**

Forward Current	nΑ
Storage Temperature55 to 150	°C
Operating Junction Temperature55 to 150	°C
Lead Temperature (1/16" from case for 10 sec.)	°C
Total Device Dissipation <sup>b</sup> 500 m	١W

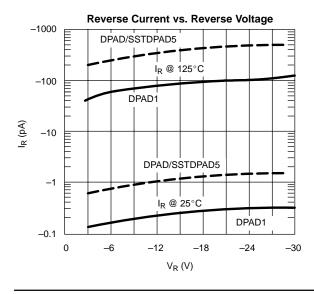
#### Notes:

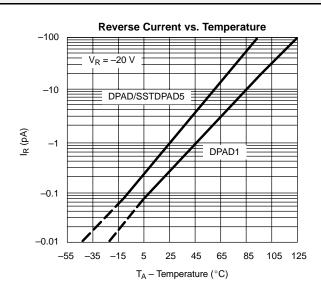
- a. T<sub>A</sub> = 25°C unless otherwise noted.
  b. Derate 4 mW/°C at 25°C.

SPECIFICATIONS (T <sub>A</sub> = 25°C UNLESS OTHERWISE NOTED)									
		Test Conditions		Limits					
Parameter	Symbol			Min	Тура	Max	Unit		
Static									
Reverse Current	I <sub>R</sub>	V <sub>R</sub> = -20 V	DPAD1		-0.2	-1	pA		
			DPAD5/SSTDPAD5		-2	<b>-</b> 5			
			DPAD5/SSTDPAD5DPAD50		<b>-</b> 5	-50			
			SSTDPAD100		-10	-100			
Reverse Breakdown Voltage	B∨ <sub>R</sub>	I <sub>R</sub> = -1 μA	DPAD1	-45	-60		V		
			DPAD5/DPAD50	-45	-55				
			SSTDPAD5/SSTDPAD100	-30	-50				
Forward Voltage Drop	V <sub>F</sub>	I <sub>F</sub> = 1 mA			0.8	1.5			
Dynamic									
Reverse Capacitance	C <sub>R</sub>	V <sub>R</sub> = -5V, f = 1 MHz	DPAD1		0.6	0.8	pF		
			DPAD5/DPAD50		1.0	2.0			
			SSTDPAD5/SSTDPAD100		2.0	4.0			
Differential Capacitance	C <sub>R1</sub> – C <sub>R2</sub>	V <sub>R1</sub> = V <sub>R2</sub> = -5 V f = 1 MHz	DPAD1		0.07	0.2			
			All Others		0.1	0.5			

### Notes:

## TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25°C UNLESS OTHERWISE NOTED)





a. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.

# **Legal Disclaimer Notice**



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